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Large directional conductivity change in chemically stable layered thin films of vanadium oxide and a 1D metal complex

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Electroactive hybrid and layered oxides and related materials, where the inorganic phase is the host, offer the conductivity characteristics of semiconductors, has led to their use in thin film transistors and related electronic devices where the host-guest interaction offered conductivity with improved processability. We describe the synthesis and characterization of a nanocomposite that shows large conductivity anisotropy when deposited as a thin film. We made the material by inserting quasi 1-dimensional potassium tetracyanoplatinate metal complexes with insulating electrical properties in between stacked nanosheets of vanadium oxide xerogels. Detailed structural and compositional analysis using transmission electron microscopy and X-ray photoelectron spectroscopy confirms that the hybrid material forms from a topotactic reaction and the framework of the layered host oxide structure is maintained. The hybrid film demonstrates a ~1000-fold conductivity change between transport parallel and perpendicular to the film at room temperature. Temperature dependent transport measurements confirm Ohmic conduction perpendicular to the stack and small polaron hopping conduction parallel to the layering direction of the film. The conductivity anisotropy and simple synthesis demonstrates that nanostructured layered hybrids can provide alternative materials for thin film complimentary logic and resistive memory.

1. Introduction

One-dimensional conductive partially oxidized platinum polymers have been shown to have a linear chain arrangement in which the dz electron orbital of the metal atoms overlap, allowing extended electron delocalization in one dimension\textsuperscript{1, 2}. Within this class of quasi-one dimensional solids (Q1-D) the most well-known tetracyanoplatinate is K\textsubscript{2}Pt(CN)\textsubscript{4}Br\textsubscript{0.3} (Krogmann’s salt, Fig. 1, platinum potassium tetracyanoplatinate) behaves as a one-dimensional metal at room temperature; without the Br, it has a strongly insulating character\textsuperscript{2}. Incorporating this class of linear complexes, of which the tetracyano complex [M(CN)\textsubscript{4}] is a prime example, into conductive host materials could offer synthetic routes to electronic complexes in which the magnitude and mechanism of the conductivity is controlled by the degree of metal atom orbital overlap. These kinds of structural arrangements could be realized in hybrid materials where metal quantum effects such as Luttinger liquid behaviour\textsuperscript{3, 4}, Peierl’s transitions\textsuperscript{5} and charge density waves are mixed with various conduction mechanisms found in host materials\textsuperscript{6}. K\textsubscript{2}Pt(CN)\textsubscript{4} is a known and useful compound in the chemistry of platinum complexes\textsuperscript{7}, and has potential uses in new kinds of electrical circuitry based on nanoscale building blocks\textsuperscript{8}, where the metal-metal bonds can regulate the electrical and mechanical properties of the units.

In regular insulators, semiconductors and metals, the electronic response is almost independent of direction whereas in Q1-D solids enhanced electronic response occurs in specifically one direction, along the axial length of the chain via a Peierls distortion and associated transition\textsuperscript{9}. In particular, interactions between transition metal oxides and Q1-D linear chains of metal complexes can form layered materials with complex conduction characteristics\textsuperscript{10, 11}, where the intercalation of the metal is known to enhance, affect or even suppress CDW observation\textsuperscript{12} and strongly correlated electronic effects.

When the building blocks of an electronic material consist of an inorganic and an organic phase where the resulting structure and properties are strongly correlated to their interaction\textsuperscript{13-16}. A judicious choice of organic and inorganic phases (semiconducting, self-assembling, intercalating, insulating, passivating) can allow rational design for added functionality\textsuperscript{16}. The resulting hybrid structure can be well defined\textsuperscript{16-18} with strong, specific organic-inorganic and organic-organic interfaces. Integrating layered nanostructures in their 1D form into electronic devices\textsuperscript{19} may expand the field of advanced materials for electronics\textsuperscript{20}. For example, the versatile redox-dependent electronic properties and intercalation properties of vanadium oxide\textsuperscript{21} and related materials\textsuperscript{22}, has fostered its use in numerous applications in catalysis\textsuperscript{27}, Li- and Na-ion batteries\textsuperscript{28-29}, electrochromic materials, field-effect transistors (FETs)\textsuperscript{30} and photoconductors\textsuperscript{31}, gas sensors, spintronic and piezoelectric devices\textsuperscript{32}, actuators\textsuperscript{33} and others\textsuperscript{34}. Previous investigations of hybrid organic-inorganic vanadium oxide-based structures\textsuperscript{35} and single phase vanadium oxide thin films\textsuperscript{36} have shown that polaron hopping conduction\textsuperscript{37}

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through the oxide is maintained, but the organic phase offers mainly structural modifications rather than a direct influence on electronic conduction characteristics. Improvements in thin film growth and deposition methods, together with strongly correlated electronic behaviour in transition metals including metal-insulator transitions, make multivalent oxides potentially very useful for technology applications. Vanadium oxides are being considered as oxide semiconductor channel materials and have demonstrated a promising degree of electrostatic control and gating effects in the metal-insulator transition for switches and logic elements using VO2.

We show here how Q-ID linear chain metal complexes can form vanadium oxide electronic material similar to an intercalated V2O5 xerogel, with excellent long term chemical and structural stability. The Q-1-D complex is poised to be placed between n-type conducting V2O5 sheets, and we show using detailed microscopy and spectroscopy that a topochemical reaction maintains the host structure. We demonstrate, that the hybrid exhibits strong conductivity anisotropy at room temperature and importantly, without a phase change of the V2O5. A >1000-fold conductivity flip occurs depending on whether electronic conduction is along the film or through the thickness of thin film. Our results demonstrate that the conduction flip is due to a switch between higher conductivity polaronic transport along the film layers (parallel to the substrate) and much more resistive Ohmic transport perpendicular to the stack, caused by the presence of the Q1-D chains. Spectroscopic analyses confirm that the material remains chemically and structurally stable for at least a period of >2 years.

2. Experimental section

Microwave-assisted hydrolysis of orthorhombic V2O5 with t-butyl alcohol was accomplished using a frequency of 1.225 GHz pulsed with a period of 30 s for 1 h. To synthesize K2[Pt(CN)4], 1.0 g of K2PtCl4 was dissolved in 150 mL of water. Subsequently, 4 equiv. of KCN were added in small portions for 15 mins. Within an hour the initially red solution became colourless. The resulting solid was dissolved in a minimum volume of water at 338 K and placed in an ice bath. The white needle-like crystals that formed were filtered and washed with water. The intercalation product was obtained by mixing K2[Pt(CN)4] with V2O5 xerogel in a molar ratio 0.5:1 (1.83 × 10^{-4} mol of K2[Pt(CN)4] in 3.66 × 10^{-4} mol of V2O5). This resulted in the formation of the bourbon red precipitate product which was separated from the supernatant solution, centrifuged and dried at room temperature, and stored in an argon environment.

X-ray powder diffraction characterization was performed using a Siemens D5000 diffractometer (Cu-Kα, λ=1.5418 Å, operation voltage 40 kV, current 30 mA). The scanning electron microscopy (SEM) analysis was performed using a Hitachi S4800 FESEM. Chemical composition was determined by elemental chemical analysis (SISONS model EA-1108), and thermal analysis (TA) was conducted in a NETZSCH Model STA 409 thermogravimetric system with a microprocessor driven temperature control unit and a TA data station from 273 to 823 K at 10 K min⁻¹.

Transmission electron microscopy (TEM) was conducted using a JEOL 2100F FEGTEM and a JEOL 2011 TEM operating at 200 kV. X-ray photoelectron spectroscopy was performed using a Kratos Axis 165 equipped with a monochromatic Al source (Kα = 1486.58 eV) with a spot size of 1 mm. The source power was 150 W.

Raman scattering measurements were conducted using a Horiba Dilor XY LabRAM spectrometer equipped with an Olympus BX40 confocal microscope. Excitation was provided by a 633 nm He–Ne laser. The spectra were typically acquired with a 5 s exposure time and a laser power density <45 µW µm⁻².

Electrical conductivity measurements were taken in central regions formed from a consistent drying line and deposition thickness, away from thinner edges. For detail on effects of withdrawing from sol-gel solutions, see Ref. 56. Briefly, viscous composite sol-gel is extruded at fixed rate from a source sol at an angle. Tear-drop deposits at the electrode edges were ignored. Layers were made intentionally thick (~500 nm - 5 µm) so that top contacts using 4-probe measurements and side contacts (involving the intercalated complexes) were electrically addressable. Gold wire was contacted to the surface using conductive gold paste. Bottom contacts were made for perpendicular charge transport through the film and 2- and 4-probe measurements along the layering direction of the thin film deposit. A gold-coated glass covered in a SnO2 membrane was lithographically defined to have 4 nodules of gold exposed on the substrate. I-V curves and temperature-dependent conductivity measurements were made using a Keithley 2420 dc voltage source and an Agilent 34401A Digital Multimeter in a Faraday cage.

3. Results and discussion

3.1 Electrical conduction anisotropy in V2O5/Q1-D thin film stacks

First, we detail the strongly anisotropic electrical characteristics of the Q1-D-vanadium oxide thin films and subsequently correlate these findings to a detailed structural analysis of the hybrid thin film. In the first experiment, 2-probe measurements were made from side-contacting the vanadium oxide, so the influence of the metal complex within the conducting framework could be established. Figure 1a,b shows the corresponding I-V curves at room temperature, and we note that the profile follows a symmetrical thermionic emission-like profile with symmetry in the forward and reverse bias current where all conducting sheets are electrically addressed. Figure 1b shows the I-V curves for direct conductivity measurements through the film thickness (by comparison to measurements along the film where all the layers are addressed). Figure 1c shows the molecular structure of the V2O5 layers and the Q1-D metal complex.

We observe a large anisotropy in overall conductivity, with a ~1000-1300x decrease (from 3.2 × 10^{-2} S cm⁻¹ to <5 × 10^{-3} S cm⁻¹) in conductivity perpendicular to the layering for a deposit that is 5 µm thick compared to conductivity along the plane of the deposit. The response is linear (Ohmic) indicating that the stack is less sensitive to the polaron hopping mechanism through the vanadium oxide framework itself. We attributed this anisotropy to the presence and blocking conduction characteristics of the intercalated Q1-D metal complex solid between the nanosheets of V2O5 of the crystallized sol-gel deposit. Control measurements of the conductivity of the pristine xerogel in both directions (parallel and perpendicular), shown in Supplementary material Fig. S1,
shows only a small variation in conductivity with no change in the mechanism of charge transport for similarly thick deposits. Uniquely, with the complex intercalated, perpendicular transport is Ohmic and far more resistive. As will be detailed in subsequent sections, this material is not simply a mixture of both the Q1-D and V$_2$O$_5$, a strong host-guest interaction maintains the layered structure of the xerogel, with the Q1-D complex dominating charge transport perpendicular to the layering.

![Diagram](image)

**Fig. 1** Schematic arrangement for transport measurements of the K$_2$[Pt(CN)$_6$]$_{x}$V$_2$O$_5$ thin film. (b) I-V curves acquired parallel to (along) the film at RT and 373 K, and perpendicular to the thin film at RT. (c) CPK model of an intercalated structure with the Q1-D molecule oriented along the a-axis of the V$_2$O$_5$ unit cell. The structure is drawn as polygons.

Variations of 100-1000× have been reported in macroscopic cm-sized organic-inorganic materials compressed into highly disordered pellets where inter-grain boundaries alter the effective conduction pathways.$^{57, 58}$ Other techniques include using poly (ethylene oxide) (PEO) or the oxide hydration states to widen the gap between V$_2$O$_5$ layers, but for deposits encapsulated with sheaths of polymer$^{59}$ Here, the 1-dimensional solids of insulating nature allow large directional conduction anisotropy while leaving the deposit as a thin film, unaltered mechanically or physically. As the oxide film is fully aged, increases in conductivity that are known to occur during ageing over a period of years, are avoided. By designing a 4-probe contact area on an insulating substrate (see Fig. 1a), and similarly on the top of the resulting deposit, we were able to probe temperature dependent conductivity along and through the thin film, while extracting the contribution of contact resistance to the deposit. The intrinsic resistance along the stack is 13.2 MΩ, and the contact resistance is 0.56 MΩ. An intrinsic conductivity of 2.9 $-$ 5 x 10$^{-2}$ S cm$^{-1}$ was obtained for several nanosheets stacks, typically of 500 nm -5 μm thickness. Through the thickness of the deposit however, 4-probe data confirm the 2-probe measurements where a ~1000-fold reduction in conductivity is found. Along the stack, the conductivity is marginally higher than bulk V$_2$O$_5$ but of the same order of magnitude, while showing a large anisotropy perpendicular to the layers.

The transport in both directions was also measured in the range 77 – 400 K, but kept below temperatures where a metal-insulator transition or other thermalized effects involving electron-phonon coupling in V$_2$O$_5$ would complicate the effect of the intercalated Q1-D complex. Typically, polaron hopping transport (conductivity) in vanadium oxides follows a power law according to \( \sigma = \sigma_0 \exp \left(-\frac{E_0}{kT}\right)^{\beta} \), where \( T_0 \) is a measure of the electronic disorder in the film. The value of \( \beta \) was estimated following the approach of Bharadwaja et al.$^{36}$ to be in the range 0.23 – 0.27, consistent with 2D Mott variable range hopping (VRH) conduction.

Figure 2 shows the data plotted in accordance with a variable range hopping model with \( \beta = 0.25 \) for transport along the layering direction. Measurements were made using 4-probe measurements by contacting alternate pairs of electrodes.

![Graph](image)

**Fig. 2** (a) Variation in conductivity with temperature in the range 77 – 400 K for Q1-D intercalated V$_2$O$_5$ thin film stacks. The inset show a CPK space-filling model of the Q1-D intercalated V$_2$O$_5$ with the Pt-Pt bond axis parallel to the a-axis of V$_2$O$_5$. (b) Conductivity determined from 2-probe devices for electrode pairs A and B parallel to the layering direction and 2-probe data acquired through the thin film stack. Each data point is an average of 20 measurements for each direction from 4 separate samples.

The consistency shows that directional resistance change is not found in-plane. For variable range hopping in transition metal oxides$^{60}$ with multivalent impurities, the conductivity based on carriers hopping a distance \( R \) from occupied levels to adjacent, vacant ones without any applied potential or field, is approximated by

\[
\ln \sigma = \ln \left(\frac{\nu e^2 C (1 - C)}{kRT}\right) + \left(2\alpha R - \frac{E_{\text{hop}}}{kT}\right)
\]

where \( \alpha \) is the inverse localization length of a charge carrier, \( \nu_0 \) is the phonon frequency, \( C \) is the concentration ratio V$^{4+}$/V$^{5+}$, and \( E_{\text{hop}} \) is the energy associated with a polaron hop from occupied
to free energy levels, separated by a distance \( R \). Fitting Fig. 2 shows more than one slope, leading to a dispersion of activation energies for Q1-D intercalated V\(_2\)O\(_5\) in the range \( E_{\text{act}} \approx 0.19 \sim 0.24 \) eV parallel to the layering over the temperature range investigated, which is consistent with 2D Mott-like theory. Unlike the xerogel, this hybrid has Q1-D complex chains in specific locations throughout the structure, which we suggest based on measurements detailed below, are intercalated into the host matrix. While the packing density of the Q1-D chains is not known, preferential electronic texturing whereby the majority of intercalated chains, such as those horizontally aligned along the \( a \)-axis of the V\(_2\)O\(_5\) unit cell, could account for the small variation in hopping exponents in-plane, as shown in Fig. 2a, although detailed molecular dynamics and periodic density functional theory calculations would need to be employed to probe this effect in detail.

We do note, however, that other VRH conduction mechanisms could apply, specifically when considering the Coulomb interactions between localized charges arising from multiple valence states. Since wavefunction overlap is possible in closely spaced multivalent vanadium centers, Anderson localization is likely not a factor and no Coulomb gaps exist that hinder the probability of polaron formation and hopping of charges. The range of exponents almost spans the 3D and 2D Mott-like theories, and we believe this is related to the inclusion of the insulating Q1-D metal complex chains; the xerogel without any intercalants has a characteristic 3D Mott character. However, for \( \beta = 0.25 \) or very close to it, variable range hopping occurs through a constant 2D density of states. For measurements that have exponents larger than 0.25, the likelihood is that the reduction of the V\(_2\)O\(_5\) (and thus site to site impurity concentration) is not identical at the molecular level throughout a deposit of several cms in surface area. Changes in hopping distances could arise if the degree of Q1-D packing was either reduced or non-uniform in places throughout the interlayer spacing. As will be shown below, some regions of the thin film are locally less crystalline, and we believe this contributed to the slight variations in temperature dependent (higher) conductivity parallel to the layering.

The observation of recrystallized V\(_2\)O\(_5\) nanocrystals, detailed below, within the stable and fully aged intercalated composite can act as localized concentrated hopping sites within the V\(_2\)O\(_5\)-Q1-D nanosheet stacks, but its effect in various granular thin films, nanotubes, and particularly vanadium oxide has not previously been confirmed experimentally. They are ruled out as the cause of the large directional change in conductance and mechanism, which is dominated by the presence of the complex inside the xerogel. Estimates of the hopping distance \( R \) and the degree of disorder \( T_0 \) possible for single crystal materials show large discrepancies particularly where the conduction is governed by material parameters (for simple and more complex host-guest systems) that are not inherent in the definition of \( T_0 \approx (3q^2/4\pi\varepsilon_0\varepsilon\alpha) \); trends in the variation of \( R \) and the inverse localization length \( \alpha \) are to an extent possible in some cases, but in the Q1-D-intercalated V\(_2\)O\(_5\) films here, the determination is complicated without detailed knowledge of the particular molecular structure of the host-guest system, its effective dielectric constant, etc.

The temperature dependence gives information on the mechanisms of conduction in general and we performed these measurements to determine if the large anisotropy in conductivity or resistivity through a thin film deposit follows a similar mechanism for V\(_2\)O\(_5\). The transport through the deposit, from Fig. 1b, is Ohmic with high average resistances \( (\sim 5 \times 10^5 \text{ S cm}^{-1}) \), which give much lower (3 orders of magnitude) conductivity compared to conduction along the plane, as shown in Fig. 2b. The conductance mechanism and values along the more conductive V\(_2\)O\(_5\) 2D nanosheets that periodically stack to make up the film, are more or less independent of the 2-and 4-probe conduction direction (Fig. 2a). Thus, the insertion of insulating Q1-D complexes results in a very large conductivity reduction when transport is perpendicular to the thin film, while current flow maintains a polaronic hopping conduction through the layers of vanadium oxide, when the Q1-D complex is present. The Ohmic and highly resistive transport perpendicular to the film has implications for bipolar switching behaviour that is not sensitive to non-linearity or rectification. Without the Q1-D complex, no directional conductivity flip is observed, and the conductance and transport mechanism along and through the pristine xerogel remain similar. Next, we describe a detailed investigation of the structure and crystallinity of the vanadium oxide oxide sheets with the Q1-D complex, so that a correlation between the directional electrical response and the structure can be determined.

### 3.3 Formation of stable, ordered Q1-D functionalized layered thin films

For many electronic investigations of thin films, the detailed structural analysis is often limited, which reduces the usefulness of the electronic data for rational design when the functional property is strongly dictated by the fine details of the structure. Here, it is critical to define the structural effect of the Q1-D complex on the nanosheets of crystalline V\(_2\)O\(_5\). The layer spacing of the dry xerogel material, with formula V\(_2\)O\(_5\)-0.5H\(_2\)O is known to be \( \sim 8.7 \) Å from extensive diffraction and spectroscopic analyses. V\(_2\)O\(_5\) is a disordered n-type semiconductor with insulating character defined by a band gap reported to be in the range \( \sim 2.25-2.3 \) eV. It crystallizes in an orthorhombic crystal structure (space group \( Pmmn \), with lattice constants determined to be \( a = 1.15 \text{ nm, } b = 0.36 \text{ nm, and } c = 0.44 \text{ nm. It is well established that this interlamellar spacing, formed between the bilayered arrangement of edge shared VO\(_5\) units\(^{66,67}\) propped apart by weak van der Waals forces (Fig. 1), varies as a function of the mole fraction of the water in the hydrated xerogel\(^{68} \)). We specifically added 1 mole of crystal water to the xerogel to create V\(_2\)O\(_5\)-1.5H\(_2\)O to trigger an expansion of the lamellar structure resulting in an increase in the layer spacing to 12.3 Å. As will be shown through more sensitive Raman scattering data, these spacings remained consistent for samples stored for a period of \( \geq 2 \) years. The (00l) peaks in Fig. 3 indicate a superlattice of V\(_2\)O\(_5\) layered slabs for the xerogel and the intercalated compound. Following correction for Lorentz polarization, Compton scattering and material absorption effects, the metal complex intercalated xerogel is found to maintain a similar overall layered structure. Low-angle XRD confirms Bragg reflections stemming from X-ray path length differences with a 12.3 Å spacing between lowest angle (00l) planes; this defines the expected interlayer spacing for the starting xerogel host.

K\(_2\)[Pt(CN)\(_5\)]\(_2\) is described crystallographically by the space group \( Pbcn \) by neutron diffraction; the crystal structure consists of nearly square planar Pt(CN)\(_5\)\(^{2-}\) groups stacked parallel to the c-
axis forming linear chains of Pt atoms (Fig. 3). We noticed that the use of a solvent disrupts the lattice, resulting in a change of Pt-Pt separation. However, when the solvent is removed, the initial colour of the complex is restored and the lattice parameters of the complex are identical to the original lattice parameters; any changes are expected then to come from interactions with the host material. In the case of the K$_2$[Pt(CN)$_4$] hydrate, simply allowing the freshly recrystallized yellow/green solid to dry on the countertop results in a slow change of the colour to white. The colour of the K$_2$[Pt(CN)$_4$] used in the synthesis was white, where the range of separation of Pt-Pt bonds is 3.1-3.7 Å, and the maximum for the optical absorption band ranges from 600 to 283 nm; Pt-Pt complexes with interatomic separations greater than 3.7 Å are typically colorless.

After the intercalation reaction, the XRD pattern of the K$_2$[Pt(CN)$_4$]$_{0.03}$V$_2$O$_5$ nanocomposite (in Fig. 3) shows a good degree of layering, consistent with its host and indicative of a topotactic intercalation reaction. The overwhelming majority of organic or other species inserted into vanadium oxide and initial V$_2$O$_5$ unit cell. (b,c) SEM images of the K$_2$[Pt(CN)$_4$]$_{0.03}$V$_2$O$_5$ and initial V$_2$O$_5$ xerogel confirming its deposition.

When measured, we find that the interlayer spacing of the composite is ~11.2 Å which is marginally less than the host xerogel. Additionally, the number and periodicity of reflection harmonics and the consistency in FWHM of the (00l) peaks confirms that the thickness of the V$_2$O$_5$ layers remains similar; the angle shift implies a narrower distance between self-similar layers after addition of the Q1-D complex. The net contraction of ~1.1 Å, however, can be affected by the mole fraction of water, and so is not likely to be dominantly affected by the intercalation of the Q1-D complex, and may stem from a range of other possible species such as [K(H$_2$O)$_6$]$^+$ or [Pt(CN)$_6$] clusters. Dehydration and some guest species have been previously shown to reduce the interlayer spacing in vanadium oxide bronzes.

The diffraction patterns shown in Fig. 3(a) exhibit characteristic double bi-layer reflections (absence of the (002) reflection) which confirms that intercalation of the Q1-D complex maintains the layered order of the host; all peaks shift by an identical amount to lower angles in the composite. An SEM image of the final product is shown in Fig. 3b, which maintains the overall morphology of the starting xerogel (Fig. 3c). The CPK models in Fig. 3a show that the Q1-D chain with their Pt-Pt chains along the a-axis of V$_2$O$_5$ can insert into the interlayer spacing of the xerogel so that the pillared square CN groups slot between vanadyl oxygen groups of the V$_2$O$_5$ lattice, which avoids a widening of the interlayer spacing. In spite of a low amount of intercalated guest, the diffraction pattern maintains the same form, indicating a relatively strong host-guest interaction, enough to produce a pillaring effect between layers or sheets of the V$_2$O$_5$ and avoids exfoliation or puckering of the layered matrix after intercalation. Although the intercalation ability of known cyanide species is not well documented, we have previously confirmed intercalation of polyacrylic acid (PAN) in its colloidal form (due to a low solubility of this polymer) in other 2D matrices such as MoS$_2$ and in a lamellar clay (bentonite). In the interlayer spacing, PAN forms cylindrical arrangements of about 6 nm diameter, defining a conformation similar to that found in the tetracyanoplattinate. Interestingly, the intercalation of PAN into MoS$_2$ is possible directly without any activated intermediate as usually occurs in that chemistry.

**Fig. 3** (a) X-ray diffraction patterns for V$_2$O$_5$ and K$_2$[Pt(CN)$_4$]$_{0.03}$V$_2$O$_5$ acquired in Bragg-Brentano geometry showing periodic Bragg reflections from the V$_2$O$_5$ layered materials. The inset to (a) shows a CPK space-filling model of the layered structure with the Q1-D molecule oriented along the c axis of the V$_2$O$_5$ unit cell. (b,c) SEM images of the K$_2$[Pt(CN)$_4$]$_{0.03}$V$_2$O$_5$ and initial V$_2$O$_5$ xerogel confirming its deposition.

Thermogravimetric analysis shown in Fig. 4 shows that a 4.4% weight loss occurs for the intercalated material at 90 °C due to dehydration, followed by a continuous weight loss up to 152 °C. At higher temperatures the nanocomposite shows an abrupt decomposition at ~177 °C with an associated weight loss of 16%. Overall, TGA analysis suggests that cyanogen gas (CN)$_2$ is expelled and solid KCN is formed. The KCN then sublimes without decomposition at ~82 °C, based on differential thermal analysis (DTA) of the K$_2$[Pt(CN)$_4$], shown in Fig. 4. Although the compositions of the gaseous reaction products could not be identified precisely, the percentages calculated from the thermogravimetric data indicate that 16% weight loss (at 177 °C) corresponds primarily to the extraction of loosely bound water and some crystal water.

**Fig. 4** Thermogravimetric analysis of the lamellar product K$_2$[Pt(CN)$_4$]$_{0.03}$V$_2$O$_5$. (Inset) Differential thermal analysis of the K$_2$[Pt(CN)$_4$], $T_g = 348-355 ^\circ$C.
Figure 5 shows TEM images of flakes of the vanadium oxide xerogel prior to any intercalation reaction. The flakes were exfoliated mechanically to avoid possible adverse changes from solvent exfoliation. In Fig. 5a-c, the layered morphology is clear and the crystal structure is confirmed as orthorhombic V$_2$O$_5$. In some cases, wider spacings are found in the lattice resolved microscopy images, wider than lattice spacings for V$_2$O$_5$ of any space group (see Fig. S2). These are directly due to Moiré interference patterns, which arise when lattice matched stacks of 2D crystalline nanosheets with unequal spacings are overlayed, or can occur due to mistatched/misoriented sheets with equal lattice spacings. Figures 5d-f show atomic resolution images from which 1, 2 and 3 layered regions of the hybrid compound are identified. The FFT analysis indicates that no misorientation of the layers on the atomic scale is found in the regions examined, which agrees with XRD evidence of a consistent layered crystal structure and morphology in the composite.

Following addition of the Q1-D complex and ageing for a period of ~2 years, the resulting structure is altered. Figure 6 shows that the layered morphology is maintained and the crystal space group of the oxide remains as Pnnm. After 2 years of ageing, the resulting structure shows some thickness variations (viewed in transmission), but the characteristic spacing between the (110) planes is maintained. Some regions of the film, however, do show reductions in crystal quality and in these regions we find through high angle annular dark field imaging (Fig. 6c,d) that V$_2$O$_5$ nanocrystallites are found randomly dispersed throughout these regions.

The composite was cast as a uniform thin film on glass to probe the structure and Raman scattering measurements were performed. In Fig. 7, we note that the original crystalline framework of the host is conserved at room temperature (the measurements were taken at laser power densities that cause negligible heating induced crystal changes in the V$_2$O$_5$). The influence of ageing on vanadium oxide is known to result in long term complete crystallization (which is especially noted in hydrolyzed vanadium alkoxides), but these ageing effects are ignored in the majority of investigations even though this crystallization occurs over a period of months to several years, and is expected have an impact on technological development. Importantly, consistency of the inorganic phase is maintained for long periods for these electronically anisotropic thin films.
V⁴⁺/V⁵⁺ mixed valency V₂O₅, and here becomes fully defined after ageing and full crystallization. The consistency in frequency in the Q1-D intercalated V₂O₅ is quite unusual, especially considering the >2 year period over which the data was captured. Notably, the frequency does not shift, which indicates a strong and stable V=O bond during ageing, with no conformation variation and consequently, no formal change in impurity center density. The ordered and lattice-matched V₂O₅ sheets remain unchanged in time with Q1-D chains intercalated between the successive stacks of V₂O₅ 2D sheets. The frequency consistency is also found for the δ(OrV₂O₇) type B₁g + B₃g shear and rotational movement between the edge-shared VO₂ sub-units that make up the bilayer V₂O₅ (Fig. 7c), confirming very high layer-on-layer order at least over the 1.1 µm² areas probed by the laser at various points on the thin film.

Figure 7d shows Raman scattering spectra for the xerogel before and after crystallization. Upon heat treatment the spectra confirm a fully developed crystal order for the vanadium oxide stack. Rapid crystallization of xerogel thin films, however, can result in delamination of the film from the substrate. When organics or indeed the Q1-D complex here are considered, rapid crystallization of the material cannot be performed, as showing in Fig. S3, where heating (but not ageing crystallization) can result in delamination. The resulting structure of the aged K₂[Pt(CN)₆]₀.5V₂O₅ is remarkable in that it maintains a very strong resemblance to the host xerogel. The vanadyl mode (V=O) does not change in length during crystallization, where a lengthening would reduce the frequency of the mode. Thus, the Q1-D complex does not alter this bond length through reduction. We note that the rocking ρ(V=O) mode at 282 cm⁻¹ is markedly affected by the Q1-D complex, by comparison to pristine xerogel. Additionally, the rocking δ(V–O–V) modes at 476 and 524 cm⁻¹ are less developed when the Q1-D complex is present, even after the V₂O₅ has reached is full crystallization.

Inelastic light scattering from intermolecular vibrations give the strongest indication of the effect of the Q1-D complex on the structure of the xerogel; it primarily affects vibrations related to edge-sharing of crystal sub-units in the orthorhombic layered structure, and the displacement (but not length variation) of the vanadyl bond. Correlation to HRTEM is possible by noting the slightly higher degree of disorder in transmission and the presence of nanoscale crystallites (Fig. 6) in the Q1-D intercalated and aged xerogel. These crystallites by definition, imply a reduction in the long range order of the crystallographic c-axis perpendicular to the layering direction not found in the xerogel, and correlate with the larger FWHM of the 145 cm⁻¹ phonon mode (and a lowering of its frequency to 143 cm⁻¹ upon intercalation of the complex) of the composite compared to the xerogel in Fig. 7.

The insertion of tetracyanoplatinitates into a V₂O₅ host framework allows a periodically sandwiched slab of alternating conductive and insulating materials, at the single molecular level. Its structure influences its electric properties due to its multivalent character, and our results shows that the composite can remain stable over at least a couple of years. The V₂O₅ conducts via small polarons (electronic environments) associated with the V⁴⁺ centers in the intercalated vanadia layers. The core level binding energies for V 2p⁹/₂, V 2p¹/₂ and O 1s acquired from nanosheets stacks are shown in Fig. 8 and Fig. S4. The V 2p core-levels are convoluted with two contributions each, assigned to V⁵⁺ (525.3 eV and 517.7 eV) and V⁴⁺ (524.1 eV and 516.2 eV). The hyperfine-split lines stem from strongly localized 3d electrons of isolated V⁴⁺ ions.

The corresponding O 1s binding energy is found at 530.7 eV from O²⁻ species with some contribution from OH⁻ and O²⁻. According to the empirical relation for multivalent (variable formal oxidation states) contributions (centroid splitting) to photoelectron emission in Fig. 8, the average vanadium oxidation state in the Q1-D intercalated V₂O₅ is ≈1.38 – 0.68[B.E.(O 1s) – B.E.(V 2p⁹/₂)] ≈ 4.83. The quantity of V⁴⁺ ions is typically assigned to reduction (nucleophile uptake of oxygen by the organic species, evidently from the shorter ~0.158 nm apical V=O bond) but from Fig. 8, we observe that the presence of OH⁻ ions prevents a high concentration of reduced V⁴⁺ species typically found for organic intercalated vanadium oxides; here, we surmise that the core-level photoemission ascribed to OH⁻ species can allow a replacement of V⁴⁺=O by O—V⁵⁺=OH⁻, leaving a slightly lower concentration of V⁴⁺ centers. Separate studies also confirmed this analysis and further suggested that the concentration is specifically lessened on the V₃ sites of the lattice which are predominantly tetravalent. The oxidation state of the Pt is found as Pt(0) and Pt(II), but is found to be difficult to quantitatively analyses in the small quantities used.

![Fig. 8 X-ray photoelectron spectroscopy of the Q1-D complex-intercalated V₂O₅ showing the binding energies for the V 2p⁹/₂ and O 1s core-levels.](image-url)
structure is considerably more complex. The values for this system are consistent with reduced V=O (oxygen vacancy defects) in theoretical and experimental investigations of very controlled V$_2$O$_5$ surfaces and deposits. The mechanism of oxygen vacancy formation in vanadium oxide has been the subject of intense debate in theoretical studies\(^8\), and its process has been confirmed through numerous spectroscopic and microscopy techniques\(^9\) such as scanning tunnelling microscopy\(^8\), transmission electron microscopy and angle resolved X-ray and ultraviolet photoelectron spectroscopies, among others\(^9\).

In spite of experimental observation of V$_2$O$_5$ nanocrystallities in the final film, these centres do not seem to contribute to a change in variable range hopping (VRH) conduction mechanism to Efros-Schlovskii VRH\(^1\), conduction, which has been found in other vanadium oxides where disorder was intentionally induced. Further work will be required to account for any variation in conduction mechanism from these hybrid thin film/nanosheets systems at low (<77 K) temperatures, coupled with electronic structure and molecular dynamics models to more accurately describe the interaction between the host and guest and its detailed influence on the conduction mechanisms at the molecular level that are more difficult to assess in planar device geometries.

4. Conclusions

In summary, this work reports the synthesis and formation of a layered nanocomposite from a vanadium oxide xerogel and the Q1-D solid complex K$_2$Pt(CN)$_6$, that exhibits a large conductivity change (a factor of ~13000) depending on whether transport is across the hybrid nanosheet stacks (through its thickness) or along their layering direction on the substrate. The intercalation of these linear complexes results in a decrease in the hydrated xerogel interlayer spacing without dehydration, and examination of samples after >2 years of ageing allowed analysis of fully crystallized, chemically, structurally and electronically stable films. The mechanism of the directional resistance change was shown to vary from small polaron hopping conduction along the layering direction to more resistive Ohmic transport through the thin film. Further development using lithographically defined top and back-gated 3-terminal devices will examine in more detail the influence of this chemical modification on the electrical properties, focusing on the mechanisms of charge transfer in the Q1-D chain within a polaron conducting host, and in various gated regimes as a thin film device. This work shows that directional conductivity (or resistivity) change is possible using thin films without necessitating a metal-insulator transition or tuning of grain boundary density or other mechanical/chemical features in the composite to vary the conductivity pathway through the material\(^8\). Scope exists too for synergy in functionalization of semiconducting oxides and electrostatic and thermal control of conduction mechanisms for resistive memory or logic based thin film applications. Further development using the wide range of known organic-inorganic layered materials and oxides might allow for tunable conductors in complementary logic and to study strongly correlated electron effects at oxide interfaces.

Notes and references

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\(^{98}\) Electronic Supplementary Information (ESI) available: Supplementary I-V analysis of deposits, optical and SEM images of V$_2$O$_5$ layers. TEM analysis of the layered material crystal structure and XPS analysis of the phases. See DOI: 10.1039/b0000000z.

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